



Description:

The 2N6547 transistor is designed for high-voltage, high-speed, power switching in inductive circuits where fall time is critical. They are particularly suited for 115 and 220V line operated switch-mode applications.

Features:

High temperature performance specified for:
 Reversed biased SOA with inductive loads.
 Switching time with inductive loads.
 Saturation voltages.
 Leakage currents.

Applications:

Switching regulators.
PWM inverters and motor controls.
Solenoid and relay drivers.
Deflection circuits.

Maximum Ratings

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO (SUS)}	400	
Collector-Emitter Voltage	V _{CEX (SUS)}	450	V DC
Collector-Emitter Voltage	V _{CEV}	850 V D0	
Emitter-Base Voltage	V _{EB}	9	
Collector Current - Continuous - Peak	I _C	15 30	
Base Current - Continuous - Peak	I _B I _{BM}	10 20	A DC
Emitter Current - Continuous - Peak	I _E I _{EM}	25 35	
Total Power Dissipation at T _C = 25°C at T _C = 100°C Derate above 25°C	P _D	175 100 1	W W/°C
Operating and Storage Junction Temperature Range	T_JT_stg	-65 to +200	°C

Thermal Characteristics

Characteristics	Symbol	Max.	Unit
Thermal Resistance Junction to Case	$R_{\theta JC}$	1	°C/W
Max. Lead Temperature for Soldering Purposes 1/8" from Case for 5 Seconds	TL	275	°C

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Electrical Characteristics (TC = 25°C unless otherwise noted)

Characteristic	Symbol	Min.	Max.	Unit	
Off Characteristics (1)					
Collector-Emitter Sustaining Voltage $(I_C = 100 \text{mA}, I_B = 0)$	V _{EO (sus)}	400	-		
Collector-Emitter Sustaining Voltage ($I_C = 8A$, $V_{clamp} = Rated V_{CEX}$, $T_C = 100^{\circ}C$)	V _{CEX (sus)}	450	_	V DC	
$(I_C = 15A, V_{clamp} = Rated V_{CEO} = 100V, T_C = 100^{\circ}C)$	02/((000)	300			
Collector Cut off Current $(V_{CEV} = Rated \ Value, \ V_{BE \ (off)} = 1.5V \ DC)$ $(V_{CEV} = Rated \ Value, \ V_{BE \ (off)} = 1.5V \ DC, \ T_C = 100^{\circ}C)$	I _{CEV}	-	1 4		
Collector Cut off Current $(V_{CE} = Rated V_{CEV}, R_{BE}, = 50\Omega, T_C = 100^{\circ}C)$	I _{CER}	-	5	mA DC	
Emitter Cut off Current $(V_{EB} = 9V DC, I_C = 0)$	I _{ERO}	-	1		
Second Breakdown					
Second Breakdown Collector Current with Base Forward Biased t = 1s (Non-repetitive) (V_{CE} = 100V DC)	I _{S/b}	0.2	-	A DC	
On Characteristic (1)					
DC Current Gain ($I_C = 5A$ DC, $V_{CE} = 2V$ DC) ($I_C = 10A$ DC, $V_{CE} = 2V$ DC)	h _{FE}	12 6	60 30	-	
Collector-Emitter Saturation Voltage (I_C = 10A DC, I_B = 2A DC) (I_C = 15A DC, I_B = 3A DC) (I_C = 10A DC, I_B = 2A DC, I_C = 100°C)	V _{CE (sat)}	-	1.5 5 2.5	V DC	
Base-Emitter Saturation Voltage ($I_C = 10A DC$, $I_B = 2A DC$) ($I_C = 10A DC$, $I_B = 2A DC$, $I_C = 100 C$	V _{BE (sat)}	-	1.6		
Dynamic Characteristics					
Current-Gain-Bandwidth Product (I_C = 500mA DC, V_{CE} = 10V DC, f_{test} = 1MHz)	f _T	6	28	MHz	
Output Capacitance ($V_{CB} = 10V DC$, $I_{E} = 0$, $f_{test} = 1MHz$)	C _{ob}	125	500	pF	

Indicates JEDEC Registered Data.

(1) Pulse Test: Pulse Width = 300µs, Duty Cycle = 2%.

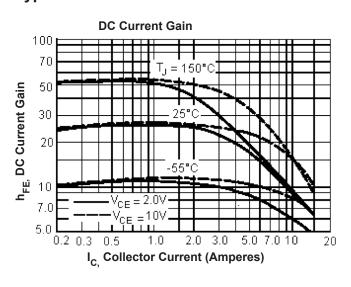


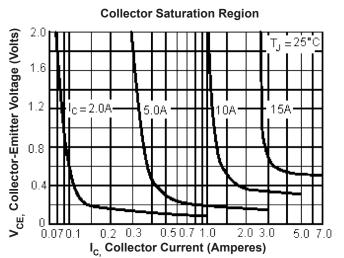


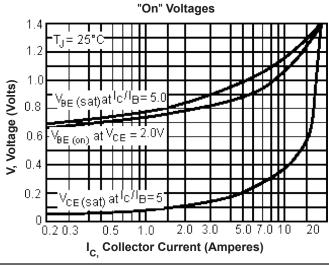
Switching Characteristics

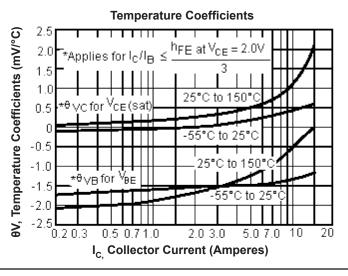
Resistive Load						
Delay Time		t _d	-	0.05		
Rise Time	$(V_{CC} = 250V, I_C = 10A,$	t _r	-	1		
Storage Time	l _{B1} = l _{B2} = 2A, t _p = 100μS, Duty Cycle ≤2%	t _s	-	4	μs	
Fall Time		t _f	-	0.7		
Inductive Load, Clamped						
Storage Time	$(I_C = 10A (pk), V_{clamp} = Rated V_{CEX}, I_{B1} = 2A, V_{BE (off)} = 5V DC, T_C = 100°C)$	t _s	-	5		
Fall Time		t _f	-	1.5	μs	
Storage Time	(I _C = 10A (pk), V_{clamp} = Rated V_{CEX} , I_{B1} = 2A, $V_{BE (off)}$ = 5V DC, T_C = 25°C)	t _s	Тур	ical 2	110	
Fall Time		t _f	Typic	al 0.09	μs	

Typical Electrical Characteristics





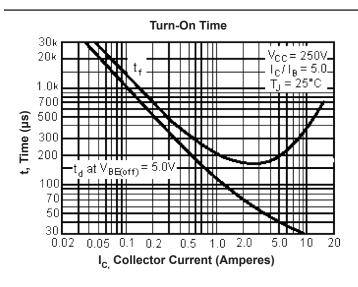


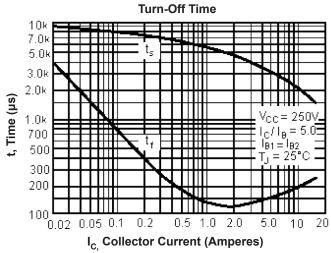


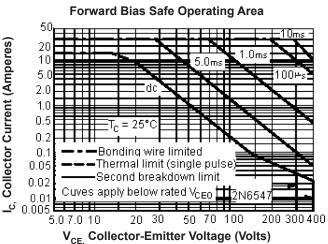
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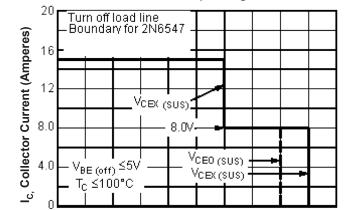




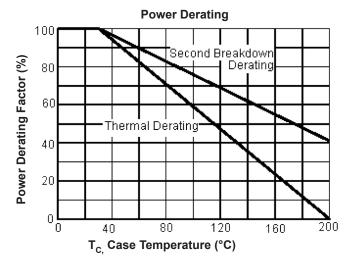








Reverse Bias Safe Operating Area



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $\rm I_C - \rm V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

200

V_{CE.} Collector-Emitter Voltage (Volts)

300

100

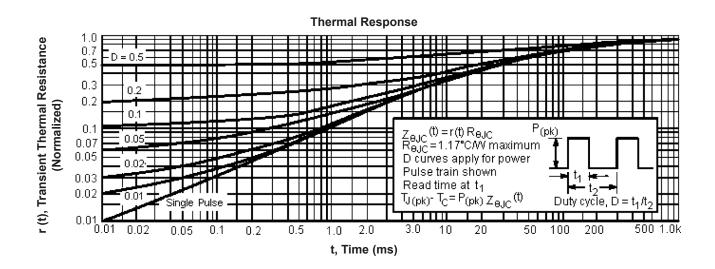
The data is based on $T_C = 25^{\circ}C$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when $T_C \ge 25^{\circ}C$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown may be found at any case temperature by using the appropriate curve. $T_{J(pk)}$ may be calculated from the data. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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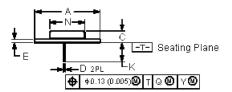
500

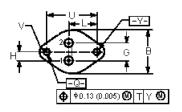


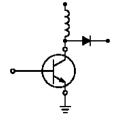


Dimensions

TO-204 (TO-3)







Dim.	Min.	Max.	
Α	1.55 (39.37) Reference		
В	-	1.05 (26.67)	
С	0.25 (6.35)	0.335 (8.51)	
D	0.038 (0.97)	0.043 (1.09)	
E	0.055 (1.4)	0.07 (1.77)	
G	0.43 (10.92) BSC		
Н	0.215 (5.46) BSC		
K	0.44 (11.18) 0.48 (12.1		
L	0.665 (16.89) BSC		
N	-	0.83 (21.08)	
Q	0.151 (3.84)	0.165 (4.19)	
U	1.187 (30.15) BSC		
V	0.131 (3.33)	0.188 (4.77)	

Dimensions: Inches (Millimetres)

Pin Configuration

Pin 1. Base

2. Emitter Collector (Case)

Part Number Table

Description	Part Number	
Transistor, NPN, TO-3	2N6547	

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